

LONG CREEPAGE TYPE HIGH ISOLATION VOLTAGE 6 PIN PHOTOCOUPLER

PS2653 PS2653L2 PS2654 PS2654L2

FEATURES

- HIGH ISOLATION VOLTAGE BV: 5 k Vr.m.s. MIN
- LONG CREEPAGE AND CLEARANCE DISTANCE 8 mm MIN
- HIGH COLLECTOR TO EMITTER VOLTAGE VCEO = 40 V MIN
- HIGH SPEED SWITCHING tr, tf = 100 µs TYP
- HIGH CURRENT TRANSFER RATIO CTR: 2000% TYP
- 6 PIN DUAL IN-LINE PACKAGE
- TAPING IS AVAILABLE

DESCRIPTION

PS2653 and PS2654 are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon Darlington-connected phototransistor in a plastic DIP (Dual In-Line Package). PS2653 has a base pin and PS2654 has no base pin. Creepage distance and clearance of leads are over 8 millimeters. PS2653L2 and PS2654L2 are surface mount type.

APPLICATIONS

Interface circuit for various instrumentations and control equipment.

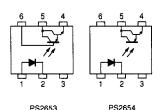
- AC LINE/DIGITAL LOGIC
- DIGITAL LOGIC INTERFACE
- TWISTED PAIR LINE RECEIVER
- TELEPHONE/TELEGRAPH LINE RECEIVER
- HIGH FREQUENCY POWER SUPPLY FEEDBACK CONTROL
- RELAY CONTACT MONITOR
- POWER SUPPLY MONITOR

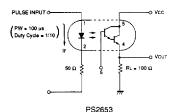
ELECTRICAL CHARACTERISTICS (TA = 25°C)

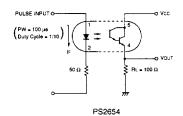
	PART NUMBER			PS2653, PS2653L2, PS2654, PS2654L2			
	SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX	
Diode	VF	Forward Voltage, IF = 10 mA	٧		1.1	1.4	
	lR	Reverse Current, VR = 5 V	μА			5	
	С	Junction Capacitance, V = 0, f = 1.0 MHz	pF		30		
Transistor	ICEO	Collector to Emitter Dark Current, VCE = 40 V, IF = 0	nA			400	
	BVCEO	Collector to Emitter Breakdown Voltage, Ic = 1 mA, IB = 0	٧	40			
	BVECO	Emitter to Collector Breakdown Voltage, IE = 100 μA, IB = 0	٧	6			
Coupled	CTR	Current Transfer Ratio ¹ , IF = 1 mA, VcE = 2 V	%	200	2000		
	VCE(sat)	Collector Saturation Voltage, IF = 1 mA, Ic = 2 mA	٧			1.0	
	R1-2	Isolation Resistance, Vin-out = 1.0 k V	Ω	1011			
	C1-2	Isolation Capacitance, V = 0, f = 1.0 MHz	pF		0.6		
	tr	Rise Time ² , Vcc = 10 V, Ic = 10 mA	μs		3		
	tr	Fall Time ² , Vcc = 10 V, Ic = 10 mA	μs		5		

1. CTR rank

K: 2300 to (%) L: 700 to 3400 (%) M: 200 to 1000 (%) 2. Test Circuit for Switching Time







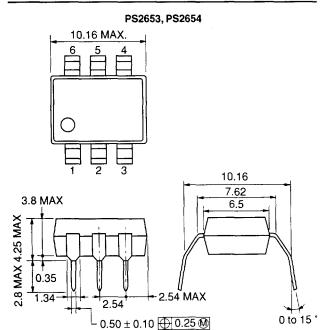
ABSOLUTE MAXIMUM RATINGS¹ (TA = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS				
Diode							
VR	Reverse Voltage	٧	6				
lF	Forward Current (DC)	mA	80				
PD	Power Dissipation	mW	150				
IF (Peak)	Peak Forward Current PW = 100 μs, Duty Cycle 1%	Α	1				
Transistor							
VCEO	Collector to Emitter Voltage	V	40				
VECO	Emitter to Collector Voltage	V	6				
Ic	Collector Current	mA	200				
Pc	Power Dissipation	mW	200				
Coupled							
BV	Isolation Voltage ²	Vr.m.s.	5000				
Tstg	Storage Temperature	°C	-55 to +150				
TOP	Operating Temperature	°C	-55 to +100				

Notes:

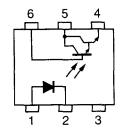
- Operation in excess of any one of these parameters may result in permanent damage.
- 2. AC voltage for 1 minute at TA = 25 °C, RH = 60 % between input (Pin No. 1, 2, 3 Common) and output (Pin No. 4, 5, 6 Common).

OUTLINE DIMENSIONS (Units in mm)



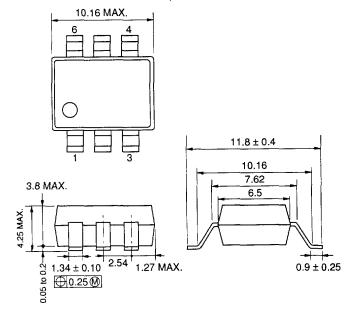
PIN CONNECTION (Top View)

PS2653, PS2653L2

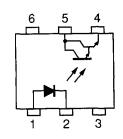


- 1. Anode
- 2. Cathode
- NC
 Emitter
- Collector
- 6. Base

PS2653L2, PS2654L2



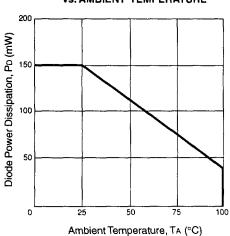
PS2654, PS2654L2



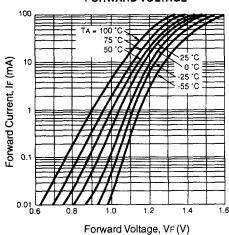
- 1. Anode
- 2. Cathode
- 3. NC
- 4. Emitter
- 5. Collector
- 3. NC

TYPICAL PERFORMANCE CURVES (TA = 25 °C)

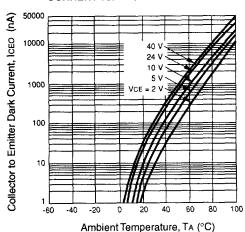
DIODE POWER DISSIPATION vs. AMBIENT TEMPERATURE



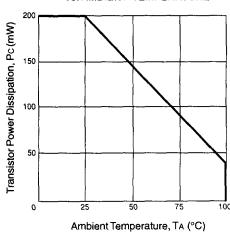
FORWARD CURRENT vs. FORWARD VOLTAGE



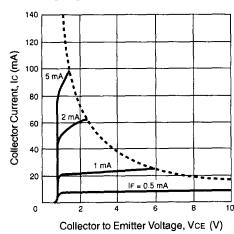
COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE



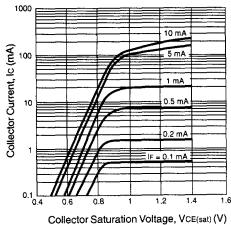
TRANSISTOR POWER DISSIPATION **vs. AMBIENT TEMPERATURE**



COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

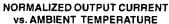


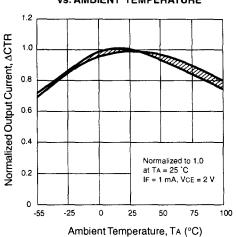
COLLECTOR CURRENT vs. **COLLECTOR SATURATION VOLTAGE**



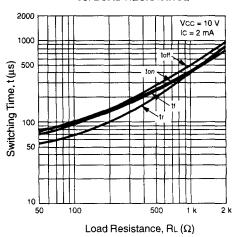
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TYPICAL PERFORMANCE CURVES (TA = 25 °C)

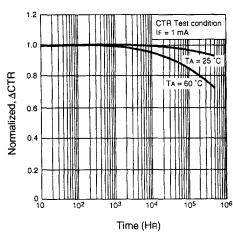




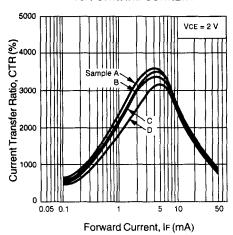
SWITCHING TIME vs. LOAD RESISTANCE



CTR DEGRADATION



CURRENT TRANSFER RATIO (CTR) vs. FORWARD CURRENT



FREQUENCY RESPONSE

